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November 2013

# **FQB44N10**

# N-Channel QFET® MOSFET

100 V, 43.5 A, 39 m $\Omega$ 

# **Description**

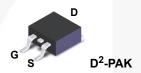
This N-Channel enhancement mode power MOSFET is • 43.5 A, 100 V,  $R_{DS(on)}$  = 39 m $\Omega$  (Max.) @  $V_{GS}$  = 10 V, produced using Fairchild Semiconductor's proprietary planar stripe and DMOS technology. This advanced MOSFET technology has been especially tailored to reduce on-state

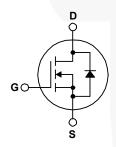
• Low Gate Charge (Typ. 48 nC) resistance, and to provide superior switching performance • Low Crss (Typ. 85 pF) and high avalanche energy strength. These devices are suitable for switched mode power supplies, active power • 100% Avalanche Tested factor correction (PFC), and electronic lamp ballasts.

# **Features**

- $I_D = 21.75 A$

- 175°C Maximum Junction Temperature Rating





# Absolute Maximum Ratings T<sub>C</sub> = 25°C unless otherwise noted.

Symbol	Parameter	FQB44N10TM	Unit
V <sub>DSS</sub>	Drain-Source Voltage	100	V
I <sub>D</sub>	Drain Current - Continuous (T <sub>C</sub> = 25°C)	43.5	Α
	- Continuous (T <sub>C</sub> = 100°C)	30.8	Α
I <sub>DM</sub>	Drain Current - Pulsed (Note 1)	174	Α
V <sub>GSS</sub>	Gate-Source Voltage	± 25	V
E <sub>AS</sub>	Single Pulsed Avalanche Energy (Note 2)	530	mJ
I <sub>AR</sub>	Avalanche Current (Note 1)	43.5	Α
E <sub>AR</sub>	Repetitive Avalanche Energy (Note 1)	14.6	mJ
dv/dt	Peak Diode Recovery dv/dt (Note 3)	6.0	V/ns
$P_{D}$	Power Dissipation (T <sub>A</sub> = 25°C) *	3.75	W
	Power Dissipation (T <sub>C</sub> = 25°C)	146	W
	- Derate above 25°C	0.97	W/°C
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Temperature Range	-55 to +175	°C
TL	Maximum lead temperature for soldering,	300	°C
'L	1/8" from case for 5 seconds.	300	

# **Thermal Characteristics**

Symbol	Parameter	FQB44N10TM	Unit
$R_{\theta JC}$	Thermal Resistance, Junction to Case, Max. 1.03		
D	Thermal Resistance, Junction to Ambient (Minimum Pad of 2-oz Copper), Max.	62.5	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient (*1 in <sup>2</sup> Pad of 2-oz Copper), Max.	40	

# **Package Marking and Ordering Information**

Part Number	Top Mark	Package	Packing Method	Reel Size	Tape Width	Quantity
FQB44N10TM	FQB44N10	D <sup>2</sup> -PAK	Tape and Reel	330 mm	24 mm	800 units

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
Off Cha	aracteristics					
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	$V_{GS} = 0 \text{ V}, I_D = 250 \mu\text{A}$	100			V
ΔBV <sub>DSS</sub> / ΔT <sub>J</sub>	Breakdown Voltage Temperature Coefficient	$I_D$ = 250 $\mu$ A, Referenced to 25°C		0.1		V/°C
I <sub>DSS</sub>	Zana Cata Valtana Duain Cumunt	V <sub>DS</sub> = 100 V, V <sub>GS</sub> = 0 V			1	μΑ
	Zero Gate Voltage Drain Current	V <sub>DS</sub> = 80 V, T <sub>C</sub> = 150°C			10	μΑ
I <sub>GSSF</sub>	Gate-Body Leakage Current, Forward	V <sub>GS</sub> = 25 V, V <sub>DS</sub> = 0 V			100	nA
I <sub>GSSR</sub>	Gate-Body Leakage Current, Reverse	V <sub>GS</sub> = -25 V, V <sub>DS</sub> = 0 V			-100	nA
On Cha	racteristics					
V <sub>GS(th)</sub>	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_{D} = 250 \mu\text{A}$	2.0		4.0	V
R <sub>DS(on)</sub>	Static Drain-Source On-Resistance	V <sub>GS</sub> = 10 V, I <sub>D</sub> = 21.75 A		0.03	0.039	Ω
9 <sub>FS</sub>	Forward Transconductance	V <sub>DS</sub> = 40 V, I <sub>D</sub> = 21.75 A		30		S
Dynam C <sub>iss</sub>	ic Characteristics Input Capacitance	V <sub>DS</sub> = 25 V, V <sub>GS</sub> = 0 V,		1400	1800	pF
C <sub>oss</sub>	Output Capacitance	f = 1.0 MHz		425	550	pF
C <sub>rss</sub>	Reverse Transfer Capacitance			85	110	pF
Switchi	ing Characteristics					
t <sub>d(on)</sub>	Turn-On Delay Time	V - 50 V I - 42 5 A		19	45	ns
t <sub>r</sub>	Turn-On Rise Time	$V_{DD} = 50 \text{ V}, I_{D} = 43.5 \text{ A},$ $R_{G} = 25 \Omega$		190	390	ns
t <sub>d(off)</sub>	Turn-Off Delay Time	1\(\text{G} = 20 \(\text{sz}\)		90	190	ns
t <sub>f</sub>	Turn-Off Fall Time	(Note 4)		100	210	ns
Qg	Total Gate Charge	V <sub>DS</sub> = 80 V, I <sub>D</sub> = 43.5 A,		48	62	nC
Q <sub>gs</sub>	Gate-Source Charge	V <sub>GS</sub> = 10 V		9.0		nC
Q <sub>gd</sub>	Gate-Drain Charge	(Note 4)		24		nC
Drain S	Source Diede Characteristics as	nd Maximum Patings				
l <sub>S</sub>	Source Diode Characteristics and Maximum Ratings  Maximum Continuous Drain-Source Diode Forward Current				43.5	Α
I <sub>SM</sub>	Maximum Pulsed Drain-Source Diode F				174	Α
V <sub>SD</sub>	Drain-Source Diode Forward Voltage	V <sub>GS</sub> = 0 V, I <sub>S</sub> = 43.5 A				V

# $Q_{rr}$

t<sub>rr</sub>

- 1. Repetitive rating : pulse-width limited by maximum junction temperature.
- 2. L = 0.42 mH, I<sub>AS</sub> = 43.5 A, V<sub>DD</sub> = 25 V, R<sub>G</sub> = 25  $\Omega$ , starting T<sub>J</sub> = 25°C. 3. I<sub>SD</sub>  $\leq$  43.5 A, di/dt  $\leq$  300 A/ $\mu$ s , V<sub>DD</sub>  $\leq$  BV<sub>DSS</sub>, starting T<sub>J</sub> = 25°C. 4. Essentially independent of operating temperature.

Reverse Recovery Time

Reverse Recovery Charge

ns

nC

98

360

 $V_{GS} = 0 \text{ V}, I_{S} = 43.5 \text{ A},$ 

 $dI_F / dt = 100 A/\mu s$ 

# **Typical Characteristics**

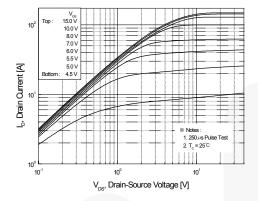


Figure 1. On-Region Characteristics

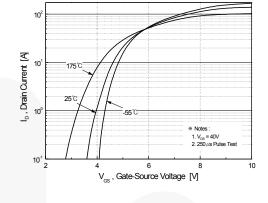


Figure 2. Transfer Characteristics

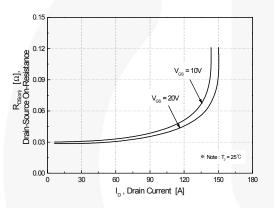


Figure 3. On-Resistance Variation vs. Drain Current and Gate Voltage

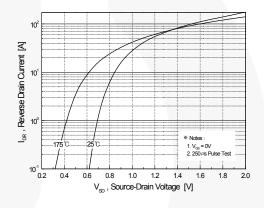


Figure 4. Body Diode Forward Voltage Variation vs. Source Current and Temperature

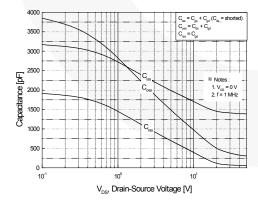


Figure 5. Capacitance Characteristics

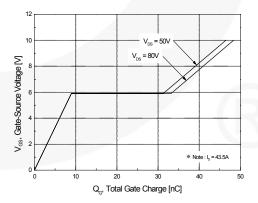


Figure 6. Gate Charge Characteristics

# 12 (Normalized) 80 1.1 (Same Branch Voltage) 1.1 (Same Branch Voltage) 1.1 (Same Branch Voltage) 1.1 (Same Branch Voltage) 1.2 (Same Branch Voltage) 2.1 (Same Branch Voltage) 2.2 (Same Branch Voltage) 2.3 (Same Branch Voltage) 2.4 (Same Branch Voltage) 2.5 (Same Branch Voltage) 2.6 (Same Branch Voltage) 2.7 (Same Branch Voltage) 2.7 (Same Branch Voltage) 2.7 (Same Branch Voltage) 3.8 (Notes: 1.7 (Same Branch Voltage) 3.9 (Same Branch

-100

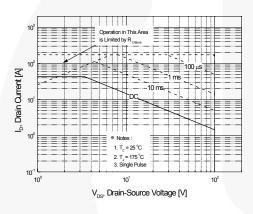
Typical Characteristics (Continued)

Figure 7. Breakdown Voltage Variation vs. Temperature

T<sub>.</sub>, Junction Temperature [°C]

150

Figure 8. On-Resistance Variation vs. Temperature



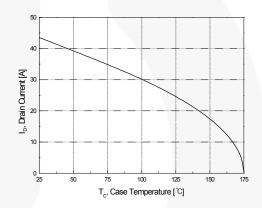


Figure 9. Maximum Safe Operating Area

Figure 10. Maximum Drain Current vs. Case Temperature

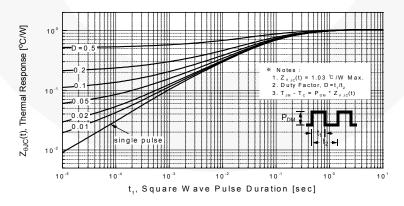


Figure 11. Transient Thermal Response Curve

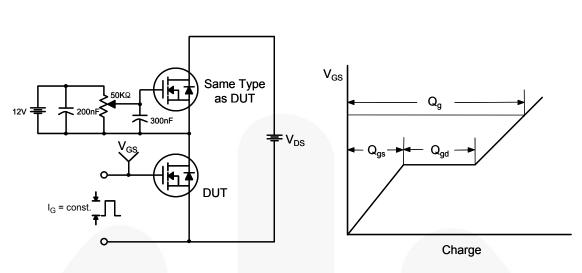


Figure 12. Gate Charge Test Circuit & Waveform

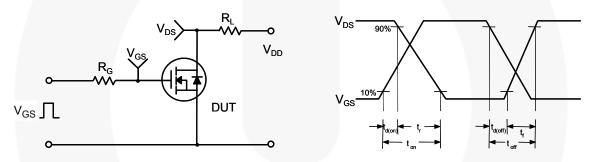


Figure 13. Resistive Switching Test Circuit & Waveforms

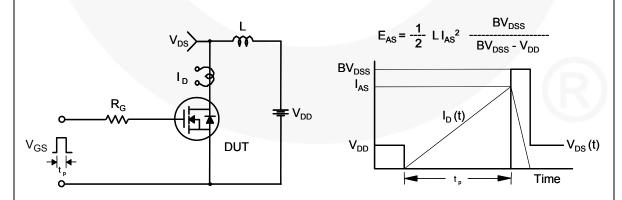
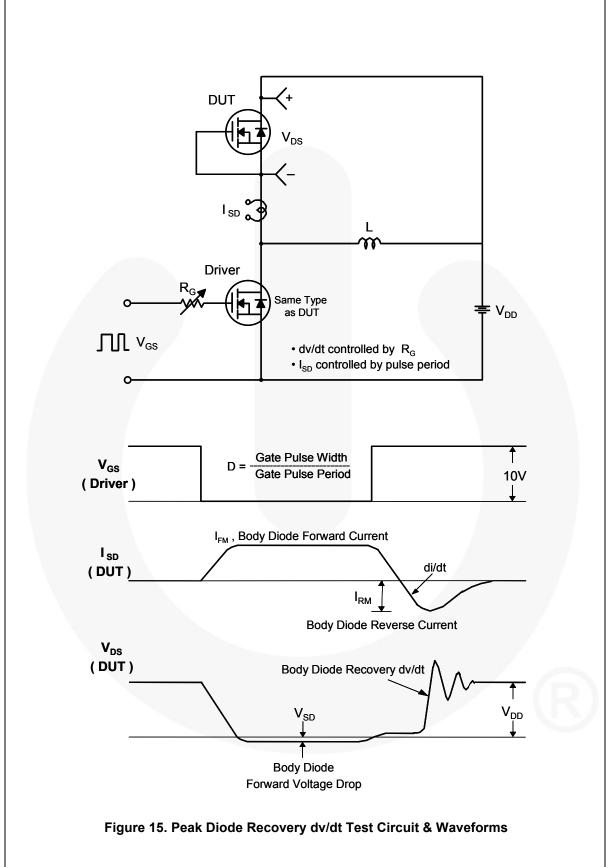


Figure 14. Unclamped Inductive Switching Test Circuit & Waveforms



# **Mechanical Dimensions**

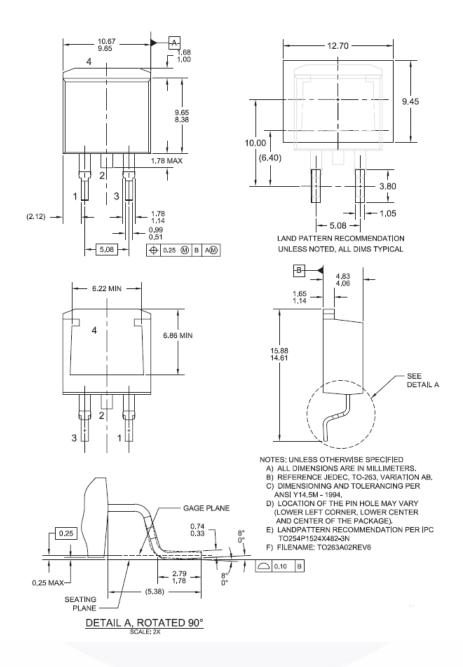


Figure 16. TO263 (D<sup>2</sup>PAK), Molded, 2-Lead, Surface Mount

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